HMC463LH250

v06.1217

GaAs pHEMT MMIC LOW NOISE AGC AMPLIFIER, 2 - 20 GHz

Typical Applications

The HMC463LH250 is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military EW, ECM & C³I
- Test Instrumentation
- Fiber Optics

Features

50 Ohm Matched Input/Output

Hermetic SMT Package

Gain: 14 dB

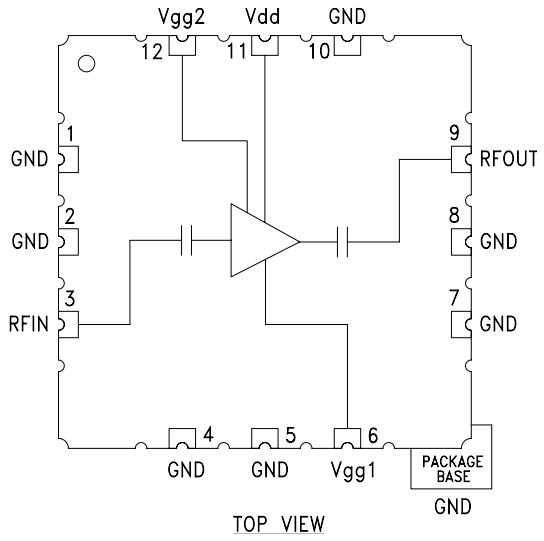
Noise Figure: 2.5 dB @ Mid-Band

P1dB Output Power: +18 dBm @ Mid-Band

Supply Voltage: +5V @ 60mA

Screening to MIL-PRF-38535 (Class B or S) Available

Functional Diagram



General Description

The HMC463LH250 is a GaAs MMIC pHEMT Low Noise AGC Distributed Amplifier packaged in a hermetic surface mount package which operates between 2 and 20 GHz. The amplifier provides 13 dB of gain, 3 dB noise figure and 18 dBm of output power at 1 dB gain compression while requiring only 60 mA from a +5V supply. An optional gate bias (Vgg2) is provided to allow Adjustable Gain Control (AGC) of 8 dB typical. Gain flatness is excellent at ±0.5 dB from 2 - 14 GHz making the HMC463LH250 ideal for EW, ECM RADAR, test equipment and High-Reliability applications. The HMC463LH250 LNA I/Os are internally matched to 50 Ohms and are internally DC blocked.

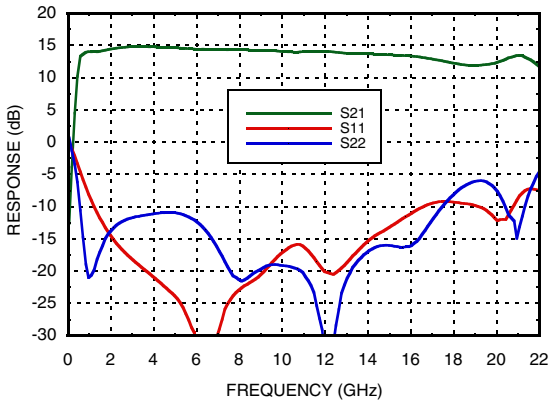
Electrical Specifications, T_A = +25° C, Vdd= 5V, Vgg2= Open, Idd= 60 mA*

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		2.0 - 6.0			6.0 - 16.0			16.0 - 20.0		GHz
Gain	11.5	14.5		9	12		8	11		dB
Gain Flatness		±0.25			±0.5			±0.9		dB
Gain Variation Over Temperature		0.010			0.010			0.010		dB/ °C
Noise Figure		3.5	5.5		2.5	4.5		4	5.5	dB
Input Return Loss		15			15			9		dB
Output Return Loss		11			15			7		dB
Output Power for 1 dB Compression (P1dB)	16	19		13	18		10	13		dBm
Saturated Output Power (Psat)		21.5			20.5			19		dBm
Output Third Order Intercept (IP3)		29			27			24		dBm
Supply Current (Idd) (Vdd= 5V, Vgg1= -0.9V Typ.)		60	80		60	80		60	80	mA

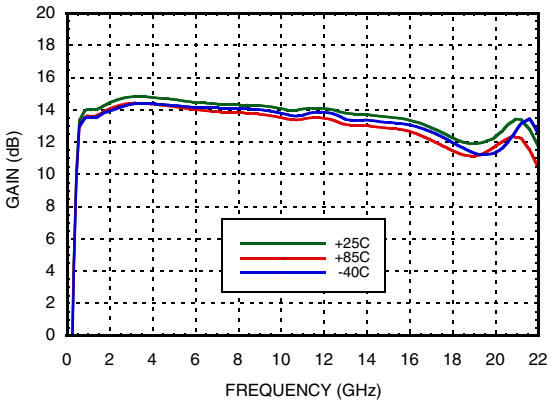
** Adjust Vgg1 between -2 to -0V to achieve Idd= 60 mA typical.*

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

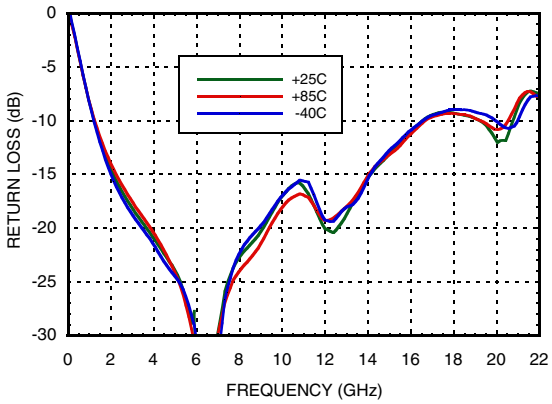
Gain & Return Loss



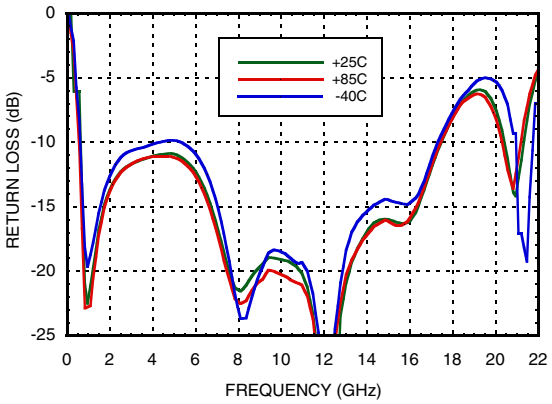
Gain vs. Temperature



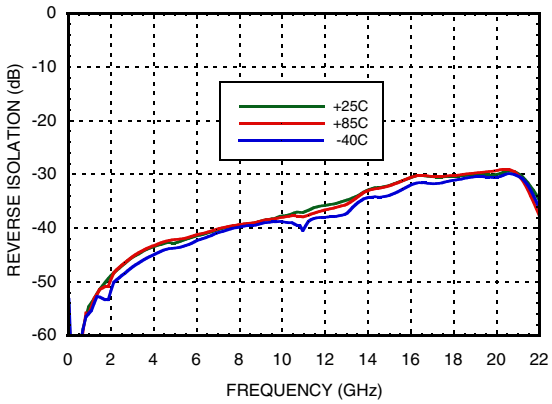
Input Return Loss vs. Temperature



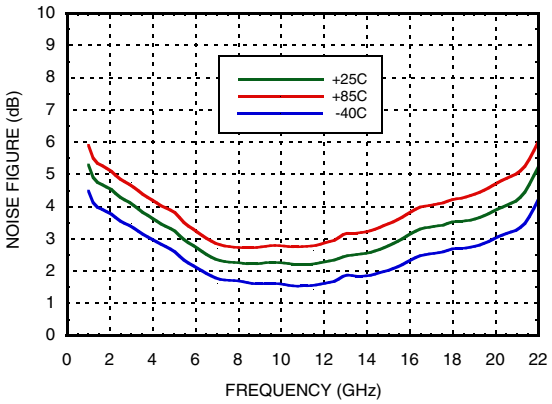
Output Return Loss vs. Temperature



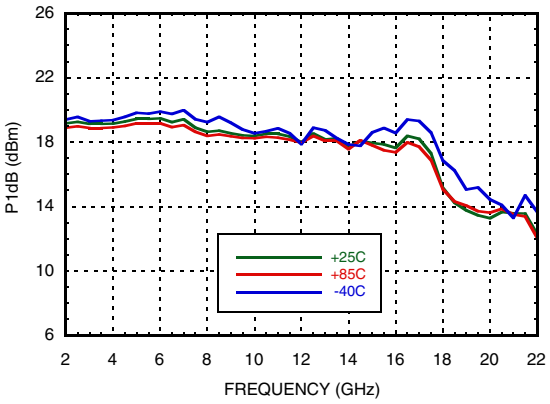
Reverse Isolation vs. Temperature



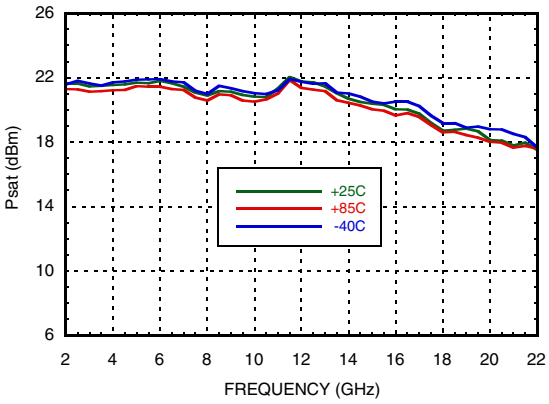
Noise Figure vs. Temperature



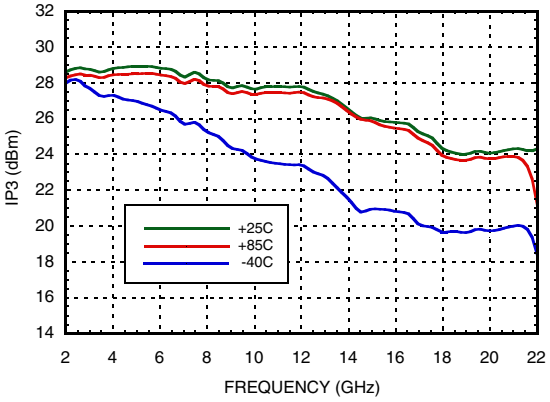
P1dB vs. Temperature



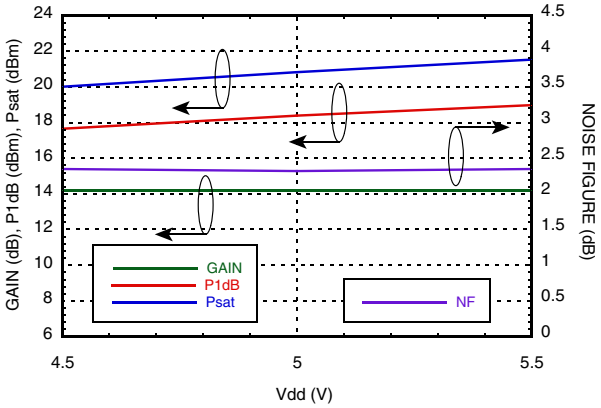
Psat vs. Temperature



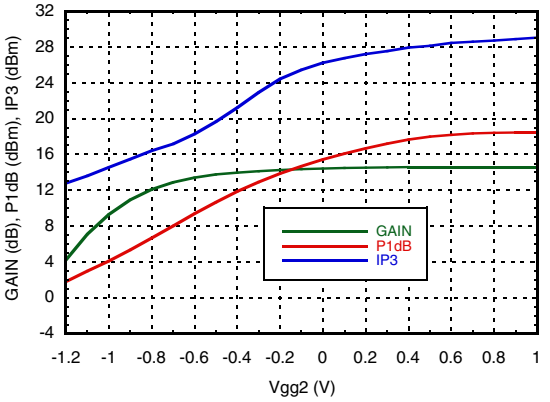
Output IP3 vs. Temperature



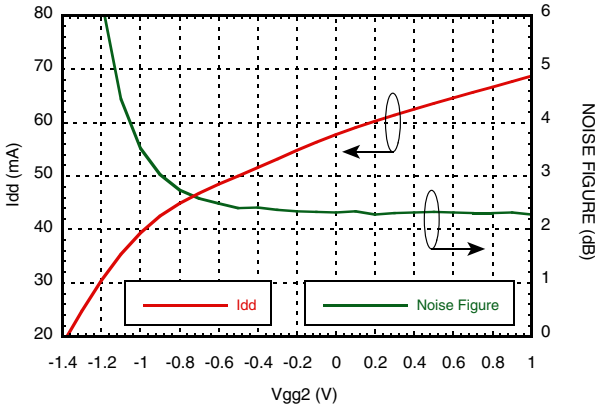
Gain, Power & Noise Figure vs. Supply Voltage @ 10 GHz, Fixed Vgg1



Gain, P1dB & Output IP3 vs. Control Voltage @ 10 GHz



Noise Figure & Supply Current vs. Control Voltage @ 10 GHz



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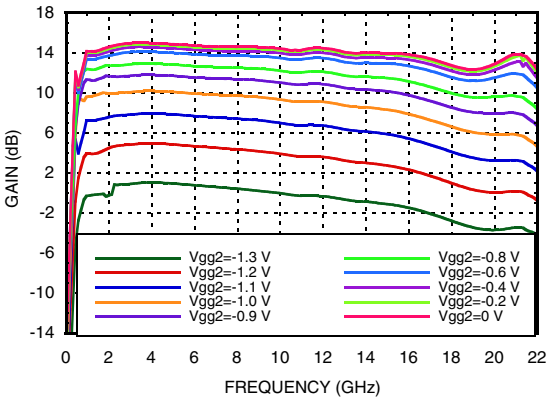
Gain @ Several Control Voltages



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

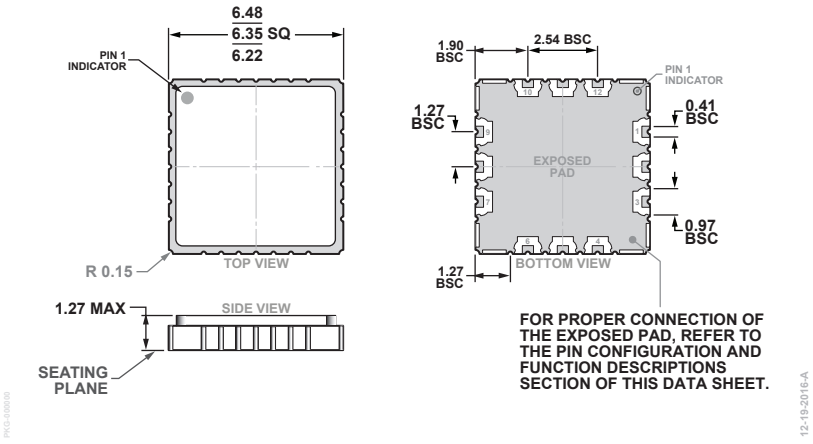
Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+9 V
Gate Bias Voltage (Vgg1)	-2 to 0 Vdc
Gate Bias Current (Igg1)	2.5 mA
Gate Bias Voltage (Vgg2)(AGC)	(Vdd -9) Vdc to +2 Vdc
RF Input Power (RFIN)(Vdd = +5 V)	+18 dBm
Channel Temperature	175 °C
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 0B - Passed 150V

Typical Supply Current vs. Vdd

Vdd (V)	Idd (mA)
+4.5	58
+5.0	60
+5.5	62

Outline Drawing



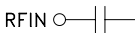
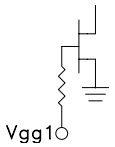
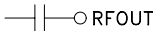
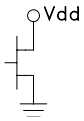
12-Terminal Ceramic Leadless Chip Carrier [LCC]
(E-12-2)
Dimensions shown in millimeters.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC463LH250	Ceramic & Kovar	Au	MSL1 [1]	H463 XXXX

[1] Max peak reflow temperature of 250 °C
[2] 4-Digit lot number XXXX

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 4, 5, 7, 8, 10	GND	Ground paddle must be connected to RF/DC ground.	
3	RFIN	This pad is AC coupled and matched to 50 Ohms.	
6	Vgg1	Gate control for amplifier. Adjust to achieve Idd= 60 mA.	
9	RFOUT	This pad is AC coupled and matched to 50 Ohms.	
11	Vdd	Power supply voltage for the amplifier. External bypass capacitors are required	
12	Vgg2	Optional gate control if AGC is required. Leave Vgg2 open circuited if AGC is not required.